

VOLTAGE REGULATORS, RELAY DRIVERS
LAMP DRIVERS, ELECTRICAL EQUIPMENT

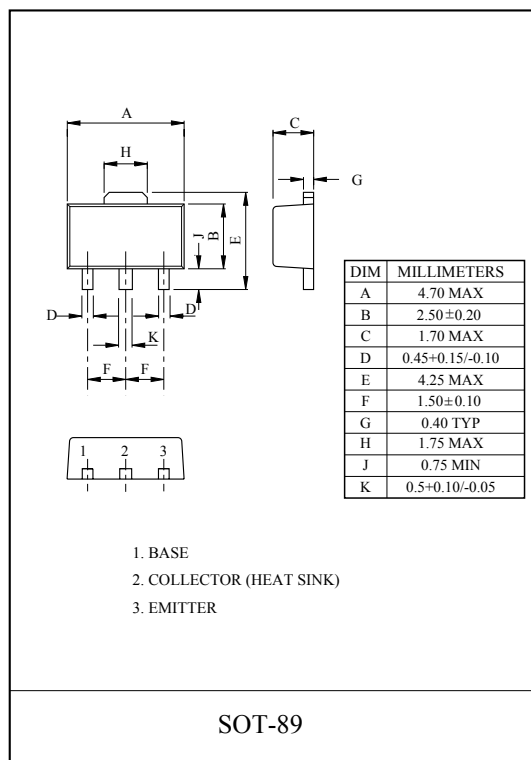
FEATURES

- Adoption of MBIT processes.
- Low collector-to-emitter saturation voltage.
- Fast switching speed.
- Large current capacity and wide ASO.
- Complementary to KTD1624.

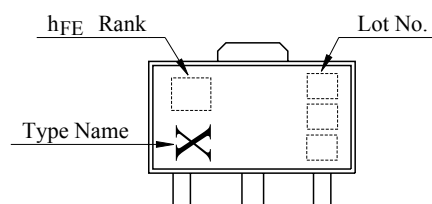
MAXIMUM RATING (Ta=25℃)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	-60	V
Collector-Emitter Voltage	V_{CEO}	-50	V
Emitter-Base Voltage	V_{EBO}	-6	V
Collector Current	I_C	-3	A
Collector Current(Pulse)	I_{CP}	-6	A
Collector Power Dissipation	P_C	500	mW
	P_C^*	1	W
Junction Temperature	T_j	150	℃
Storage Temperature Range	T_{stg}	-55 ~ 150	℃

* : Package mounted on ceramic substrate(250mm²×0.8t)



Marking



ELECTRICAL CHARACTERISTICS (Ta=25℃)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT.
Collector Cut-off Current	I_{CBO}	$V_{CB}=-40V, I_E=0$	-	-	-1	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=-4V, I_C=0$	-	-	-1	μA
DC Current Gain	$h_{FE}(1)$ (Note)	$V_{CE}=-2V, I_C=-100mA$	100	-	400	
	$h_{FE}(2)$	$V_{CE}=-2V, I_C=-3A$	35	-	-	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=-2A, I_B=-100mA$	-	-0.35	-0.7	V
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=-2A, I_B=-100mA$	-	-0.94	-1.2	V
Transition Frequency	f_T	$V_{CE}=-10V, I_C=-50mA$	-	150	-	MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=-10V, f=1MHz$	-	39	-	pF
Switching Time	Turn-on Time	<p>PW=20μs DC≤1% -10I_{B1}=10I_{B2}=I_C=1A</p>	-	70	-	nS
	Storage Time		-	450	-	
	Fall Time		-	35	-	

Note : $h_{FE}(1)$ Classification A:100 ~ 200, B:140 ~ 280, C:200 ~ 400

